

Dual channels ± 100 V, 3 A linear amplifier and 2 A pulser transmitter



Product status link

[STHV200](#)

Product summary

Order code	STHV200Q
Package	QFN-7x7-48 leads
Packing	trail

Product label



Features

- 0 to ± 100 V operative supplies
- Two independent channels
- Linear driver
 - Quad-gain settings: 24, 32.5, 36, 39 dB
 - High harmonics performances
 - High-gain bandwidth up to 20 MHz
 - No diodes on output node
 - Programmable DC current consumption
 - Saturation peak current up to 3 A
 - Fast turn-on/off time
- Pulser driver
 - 3 independent levels
 - 0.5, 1, 1.5 or 2 A programmable saturation peak current
 - Programmable continuous wave (CW) and elastography mode to reduce current consumption
- Clamp circuit
 - Real-to-zero active clamp with no DC consumption
 - 1 A saturation peak current
- TR switch circuit
 - 9.8 Ω on-resistance
 - No DC consumption
 - Multiplexing function
- Strong recirculation current protection
- Anti-memory circuit
- Auto-diagnostic function via a single interrupt pin
 - Thermal protection
 - Output short-circuit protection
 - Undervoltage checks
 - Wrong communication check
- Six registers available (8-bit each)
 - SPI protocol
 - Just a few passive components needed
 - Very-low package thermal resistance
 - Latch-up free due to HV SOI technology

Application

- Medical ultrasound imaging
- NDT ultrasound transmission
- Piezoelectric transducers driver
- Industrial

Description

The STHV200 is a fully integrated high-voltage driver including both a dual-channel linear and a dual-channel pulser driver. Pulser and linear share the same high-voltage output node XDCR and allow the user to select which output stage to use according to each specific application. This solution allows to optimize the final performances in terms of flexibility, harmonic contents, and power consumption, meeting the most demanding needs for the end application. The device can support a wide range of operating modes as pulsed wave (PW), continuous wave (CW), and elastography.

Each linear driver is a non-inverting configuration operational amplifier (op-amp) with four programmable gains (39 dB, 36 dB, 32.5 dB, and 24 dB) providing in this way the best performances for the output signal in a range between 1 V_{pp} and 180 V_{pp}. Linear drivers have been designed to optimize harmonic and noise performances thanks to a bandwidth up to 20 MHz when the maximum gain is set. Bandwidth increases reducing the gain and it reaches 25 MHz with the minimum gain setting. Each op-amp drives directly the corresponding XDCR output node without any diode connections, generating a very clean output signal and minimizing odd distortion. An internal circuit fully isolates the output to its parasitic capacitances during pulser driver activity. Fast turn-on and off times of 1.8 μ s and 0.6 μ s make the device suitable also for near-field images. A new and dedicated structure, named "active diodes", mitigates the glitch injection during the linear turn-on/off.

Pulser drivers are designed in a half-bridge configuration with a programmable saturation current (0.5 A, 1 A, 1.5 A, and 2 A) for both high-side and low-side. The generated output voltage can vary from 2 V_{pp} up to 200 V_{pp}. A real-to-zero Clamp structure with a current capability of 1 A can directly force the output node to ground. Users can fine-tune the delays of both positive and negative edges and also choose a dedicated setting for CW and elastography mode, thus optimizing the performances and the power consumption in each operative condition.

When STHV200 is used in linear mode, each individual output channel can pulse between high-voltage supplies (positive or negative, HVP_L or HVM_L), using the linear driver. When STHV200 is used in pulser mode, the waveforms generated are described as sequences of states. With each state, it is possible to configure each individual output channel to be connected to high-voltage supplies (positive or negative, HVP_P or HVM_P), clamped to ground (Clamp), or left in high-impedance (HZ).

Each channel integrates a TR switch (TRSW) that connects the XDCR with a low-voltage output node (LVOUT). The TRSW is an active structure, without any DC consumption, to guarantee effective isolation during the transmit (TX) and receiving (RX) phases. The LVOUT pins can be multiplexed to reduce the receiving channels.

The STHV200 embeds also freewheeling diodes protection, which clamps the recirculating current in case of inductive output load, an anti-memory circuit, which allows to discharge all internal nodes during the Clamp state. Short-circuit protection is also implemented on the output nodes, to prevent dangerous conditions if the impedance load is lower than 5 Ω (low-resistance or high-capacitance) or in case of an unintentional short of the output pins. In addition, other internal global checks and auto-diagnostic functions are integrated into the device to ensure safe operating conditions.

SPI protocol is used to program all the functionalities of the device.

STHV200 is available in a QFN 7x7 package with 48 pins.

Revision History

Table 1. Document revision history

Date	Version	Changes
12-Dec-2022	1	Initial release.
03-Feb-2023	2	Update Features and Description.

IMPORTANT NOTICE – READ CAREFULLY

STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST’s terms and conditions of sale in place at the time of order acknowledgment.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of purchasers’ products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2023 STMicroelectronics – All rights reserved